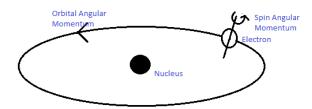
### **UNIT 3 – MAGNETISM AND DIELECTRIC**

### Magnetic moment due to orbital angular momentum of electrons:

The orbital motion of electron revolving about a nucleus is equivalent to a tiny current loop. This produces a magnetic field perpendicular to the plane of the orbit as shown in figure below



Let us consider an electron moving with a constant speed 'v' in a circular orbit of radius r as shown in fig.

Let "T" be the time taken for one revolution and 'e' be the magnitude of charge on the electron.

The current I across any point in the orbit.

Magnetic moment associated with the orbit.

$$\mu_{\rm L} = \text{current x area covered by the orbital} = IA = -\frac{\pi r^2 e}{T}$$
[Therefore,  $A = \pi r^2$ ]

Since T is the time taken for one complete revolution, the angle covered (angular displacement) in time T is  $2\pi$ .

Angular velocity 
$$\omega = \frac{2\pi}{T} \text{ (or) } T = \frac{2\pi}{\omega}$$

substituting the value of T in equation, we have

$$\mu_{L} = -\frac{\pi r^{2} e}{\frac{2\pi}{\omega}}$$

$$\mu_{\rm L} = \frac{-\pi r^2 e \omega}{2\pi}$$

$$\mu_{L} = -\frac{r^{2}e\omega}{2}$$

$$\mu_L = -\frac{r^2 e}{2} \frac{v}{r}$$

$$\mu_{L} = -\left(\frac{\text{evr}}{2}\right)$$

Hence 
$$v = r\omega$$

$$\frac{v}{r} = \omega$$

dividing and multiplying R.H.S of equation by m (the mass of the electron), we have

$$\mu_L = \frac{-evr}{2} \, x \, \frac{m}{m}$$

$$\mu_{L} = \frac{\text{-emvr}}{2m}$$

$$\mu_{L} = \frac{-\text{emvr}}{2\text{m}}$$

$$\mu_{L} = -\left(\frac{\text{eL}}{2\text{ m}}\right)$$

where L = mvr is the orbital angular momentum of the electron

#### **BOHR MAGNETON**

The magnetic moment contributed by an electron with angular momentum quantum number n = 1 is known as Bohr magnetron.

We know that

$$\mu_{\rm L} = \frac{-eL}{2m}$$
 ----- (1)

According to quantum theory, orbital angular momentum

 $\mbox{Where} \quad L = n\hbar = \left(\frac{nh}{2\pi}\right)$  substituting the value of L in equation (1), we have

$$\mu_{\rm L} = -\frac{\rm e}{2\rm m} \cdot \left(\frac{\rm nh}{2\pi}\right)$$

For n = 1, electron is in ground state, (Bohr orbit)

where n is orbital angular momentum quantum number

$$\mu_{\rm L} = \frac{eh}{4\pi m} \qquad \dots \tag{2}$$

This magnetic moment is defined as one Bohr magnetor  $(\mu_B)$ 

$$\mu_{\rm B} = \frac{\rm eh}{4\pi \rm m}$$

substituting the values in equation, we have

$$\mu_{\rm B} = \frac{1.6 \times 10^{-19} \times 6.625 \times 10^{-34}}{4 \times 3.14 \times 9.1 \times 10^{-31}}$$

$$\mu_B = 9.274 \ x \ 10^{\text{-}24}$$
 ampere metre² or Am²

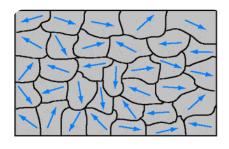
## TYPES OF MAGNETIC MATERIALS

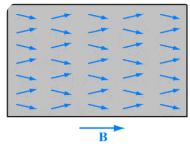
CATEGORY	DIAMAGNETIC MATERIALS	PARAMAGNETIC MATERIALS	FERROMMAGNETIC MATERIALS
Definition	These materials have no permanent dipole moment.	These materials have permanent magnetic dipole.	These materials have very large permanent magnetic dipole moment.
Electrons	<ul> <li>They have paired electrons.</li> <li>The electrons spin in opposite directions.</li> <li>Thus the net magnetic moment is zero.</li> </ul>	<ul> <li>♣ They have unpaired electrons.</li> <li>♣ They give rise to spin magnetic moment.</li> <li>♣ Thus the net magnetic moment is not zero.</li> </ul>	<ul> <li>They have more unpaired electrons.</li> <li>They give rise to spin magnetic moment.</li> <li>Thus the net magnetic moment is not zero.</li> </ul>
Absence of external magnetic field	<ul> <li>The magnetic dipole moment is zero without external magnetic field.</li> <li>All electrons have orbital and spin motion in opposite direction.</li> <li>These orbital and spin motions will be cancelled by other electron.</li> </ul>	<ul> <li>The atoms are arranged randomly in the absence of external magnetic field.</li> <li>They have equal number of <sup>+1</sup>/<sub>2</sub> spins and <sup>-1</sup>/<sub>2</sub> spins.</li> </ul>	<ul> <li>They have spin exchange interaction in the absence of magnetic field.</li> <li>The magnetic field spreads over the domain.</li> </ul>
Presence of external	The strength of the magnetic moment = the	The magnetic dipoles orient in the direction of the applied field.	The domains align parallel to the field and increase in size.
magnetic field	applied field.	Always positive and small.	Always positive and large
Susceptibility Temperature	Always negative Independent of temperature	Inversely proportional to the	Always positive and large.  Complex dependence on temperature
dependence	independent of temperature	temperature of material	Complex dependence on temperature
Magnetic lines of force	Magnetic lines of force are repelled away from the material. $B_{out} > B_{in}$	Magnetic lines of force are attracted towards the center of the material.  R. > R	Magnetic lines of force are highly attracted towards the center of the material. $B_{in} >> B_{out}$
Permeability	Less than 1.	Greater than 1.	Very much greater than 1.
Examples	Water, Bismuth and Gold.	Aluminium and Platinum.	Iron, Nickel and Cobalt.

#### DOMAIN THEORY OF FERROMAGNETISM

#### **Principle**

The group of atomic dipoles (atoms with permanent magnetic moment) organised into tiny bounded regions in the ferromagnetic materials are called magnetic domains.





(a) Unmagnetized domains

(b) Magnetized domains

When a magnetic field is applied externally to a ferromagnetic material, the domains align themselves with field as shown in fig. This results in a large net magnetization of the material.

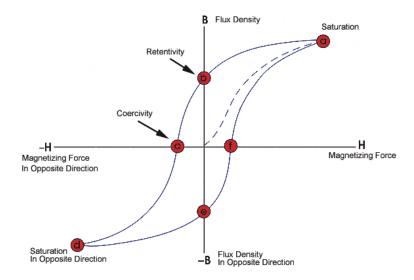
#### **Process of Domain Magnetisation**

When the external magnetic field is applied, domains align with the direction of field resulting in large net magnetisation of a material. There are two possible ways to align the domains by applying an external magnetic field.

(a) By the motion of domain walls & (b) By rotation of domains

#### HYSTERESIS LOOP

A hysteresis loop shows the relationship between the induced magnetic flux density (**B**) and the magnetizing force (**H**). It is often referred to as the B-H loop.



- A magnetizing field 'H' is applied to a ferromagnetic material.
- If 'H' is increased to H<sub>max</sub>, the material acquires magnetism and the magnetic induction 'B' increases. It is represented as –OA.
- If  $H_{max}$  is dereased to zero, the magnetic induction 'B' will not fall to zero.
- Instead magnetic induction falls to 'B'.

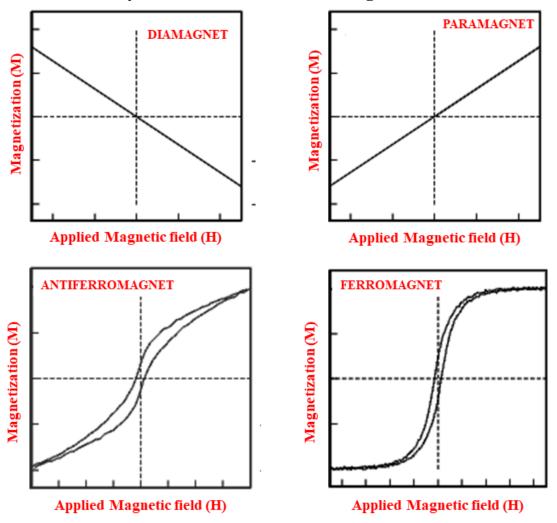
Retentivity: -

When the applied field is zero (Or) removed, the material acquires some magnetic induction called as residual magnetism or retentivity.

Coercivity: -

- To remove the residual magnetism, the magnetic field is reversed and increased to H<sub>max</sub>, represented as OC. This is called as Coercivity.
- We get the curve BCD.
- The '- H' is reduced to zero, then DE curve is formed.
- When still increasing from zero to  $H_{max}$  EFA curve is obtained.

### Hysteresis curve for various magnetic materials



## Hard and Soft magnetic materials

S.No.	Soft magnetic materials	Hard magnetic materials
1.	These magnetic materials can be easily magnetised and demagnetized	These magnetic materials can not be easily magnetised and Demagnetized.
2.	They have high permeability	They have low permeability
3.	Magnetic energy stored is not high.	Magnetic energy stored is high
4.	Low hysteresis losses due to small hysteresis loop area.  Low hysteresis losses due to large hysteresis loop area.	
5.	Coercivity and retentivity are small.	Coercivity and retentivity are large
6.	The eddy current loss is small due to its high resistivity	The eddy current loss is more due to its small resistivity
7.	The domain walls are easy to move.	The movement of domain wall must be prevented.
8.	Examples: Iron silicon alloy, Nickel iron alloy, silicon steels and ferrities.	Examples : Tungsten steel, Cobalt steel, Alini, Alnico and Cunife.
9.	They are used in electric motor, generators, transformers, relays, telephone receivers, radar and Sonar equipment's.  Small coercive force	They are used in loud speakers and electrical measuring instruments.

# DIELECTRIC MATERIALS

Dielectoric one electorically non conducting materials. Bobic difference between a dielectoric and insulation is,

- \* Born one electionically non conducting
- \* Insulation cannot Storie changes whereos a dielectric material con storie changes.
- \* AD dielectoric materials one insulatoons.

  Eg: mica, gloss, poorcelain, gloss,

  plostics and oxides of vorious metals.

PROPERTIES OF OIGLECTRIC MATERIALS

- \* Oidectaics are non-metallic materials of high presidetivity.
- \* They have losse energy gap (> 3eV)
- \* All electrons in dielectrics one tightly
- \* They have negative temperature coefficient of gresis bance
- \* High insulation gresis bance.

## DIELECTRIC CONSTANT ES

TE 18 meadours of Polarisation in the dielectorics. It is defined as snatio between assorbe permittivity of medium (E) and promittivity of spee Space (Eo) [Egr = E]

Dielectoric Permittivity (E)

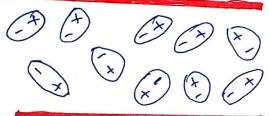
constant, En = Permittivity of Spree Space (ED)

## MOITASIAAJOA

The electrical behaviour of a dielectric material can be changed by application of external field.

when an external sield is applied to a dielectric, it exents sonce on bown positive and negative changed positively of each atom positive in bne dielectric material. The positive changes are pushed in same dispection of applied electric sield while negative changes are pushed in opposite directions.

UN BOLABISED



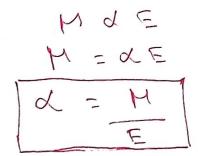
RANDOM ORIENTATION

OF DIPOLES (ELECTRIC)

The phocess of phoducing electrical dipoles in side the dielectric by application of external sield is called polonization in dielectrics.

## POLAR 12ABILITY

It is the statio of average dipole moments of applied electoric Sield. Unit is Fm2





OF DIELECTRIC

+ + + + + + + +

VARIOUS POLARISATION MECHANISMS IN DIELECTRICS

The form Polarization mechanisms which occupi in a dielectric material is,

- \* Electeraric Pologization
- \* Ionic Pologization
- \* Osientational Pologization
- \* Space charge polorization

ELECTRONIC POLARIZATION

It is due to the displacement of Positively Changed nucleus and negatively Changed electrons of an atom in opposite dispections on application of electrical sield.

Dipole moment (M) is propositional to electric Eield Striengton

MUE

M = deE

de - electronic polarizability

(1) without electoric Sield

consider an atom of dielectric

tre at centre

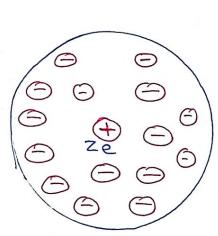
Z-atomic number

Electrons one distributed

uniformly wroughout the

atom of gradius R

chase of an electron = -Ze



INTHE ABSENSE OF FIELD

3

when no electric field is applied the centres of electron cloud and the positive nucleus one at same point and hence there is no dipole moment.

Negative choose density of an atom of

$$C = \frac{70 \text{ tol} - \text{ negative}}{\text{chosinge}} = \frac{-2e}{4 \pi R^3}$$

$$C = \frac{-3}{4 \pi R^3}$$

$$C = \frac{-3}{4 \pi R^3}$$

(ii) when electoric field applied
when the dielectoric is placed in an
electoric field of storength, F two
Applied

Phenomena occusi.

a) rodieurs fooice

tends to move the Positive

nucleus and electron cloud of

wat atom from their Positions.

Positive nucleus will move towards

me sield dispection and electron cloud move in opposite dispection.

b) Attenactive collomb force

choud which tends to maintain the eavilibrium position.

ELECTRIC FIELD

On application of electoric sield the electron cloud and nucleus more in opposite disrections and were allegated by a distance of electoric where there is a sommation of electoric dipole in the atom.

when hose two forces one early a open opposite, these will be a early in an atom.

Logientz Sogice, FL = Change x Electric

consider a spresse of madius of which encloses we the nucleus & -ve electrons.

Records of negative changes as enclosed in square of madius x

= change density (e) x volume of square

$$= \frac{3}{4} \frac{2e}{\pi R^3} \times \frac{4}{3} \pi x^3$$
 [Substituting  $e$  Snow equation  $e$ ]
$$Q_e = -2e \left(\frac{x^3}{R^3}\right)$$

$$F_{C} = \frac{1}{4\pi\epsilon_{0}} \times \frac{7\epsilon \times -2\epsilon}{x^{2}} \left(\frac{x^{3}}{R^{3}}\right)$$

$$\frac{1}{4\pi \epsilon_0 R^3} = \frac{-(2e)^2 x}{4\pi \epsilon_0 R^3}$$

AL ENVILIBAIUM, COLOUMD FOARCE & LOARNES GOACE IS

ZeE = 
$$-\left(-\frac{Z^2e^2x}{4\pi\epsilon_0R^3}\right)$$

$$x = \frac{4\pi\epsilon_0 R^3}{2e} \Rightarrow x = \frac{4\pi\epsilon_0 R^3 E}{2e}$$

The induced dipole moment

Mind = magnitude of x displacement

Mind = Zex

Interms of polonisability

\* It is brobodicious por notine of around to notine of around the Exection of around

in me material

\* Electronic Polorization occurs in all dielectric materials.



JONIC POLARIZATION

& It occups in ionic chystall

eg: Nach, KCL, KF, NaT

\* It occurs due to me displacement of Cations and anions in opposite dispections.

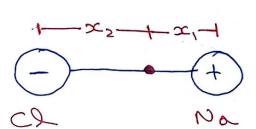
When an electric field is applied on an ionic dielectric, more is a shift of one ion with shespect to another from their mean positions.

Positive ions displace through a distance X, negative ions displace through a distance X2

net distance  $x = x, +x_2$ 

when the ions one displaced snow their mean positions in their mean positions in their subspective dispections the substopping forces appear which tend to move the ions back to their mean position.





FOR the ions restoring source, Fidx,

For -veions "  $F = x_1 \beta_1$   $\beta_1 \otimes \beta_2 \text{ one shearing forme}$   $F = \beta_2 x_2$   $\Rightarrow 3$ 

M - word of vedatine iou

7

Wo. Engular frequency

$$\beta_1 = m \omega_0^2 \rightarrow \oplus$$
 $\beta_2 = M \omega_0^2 \rightarrow \oplus$ 
 $\beta_2 = M \omega_0^2 \times \oplus$ 

Substituting  $\beta_1 \approx \beta_2 = 0$  and  $\beta_2 = 0$  and  $\beta_3 = 0$ 
 $\beta_1 = m \omega_0^2 \times \oplus$ 
 $\beta_2 = m \omega_0^2 \times \oplus$ 
 $\beta_3 = m \omega_0^2 \times \oplus$ 
 $\beta_4 = m \omega_0^2 \times \oplus$ 
 $\beta_4 = m \omega_0^2 \times \oplus$ 
 $\beta_5 = m \omega_0^2 \times \oplus$ 
 $\beta_6 = m \omega_$ 

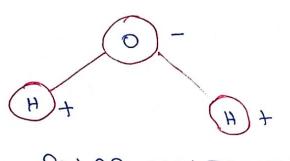
## POLAR MOLECULE

A possessive is one in which the centiste of gravity of positive changes is separated from the centre of gravity of negative changes by a finite distance.

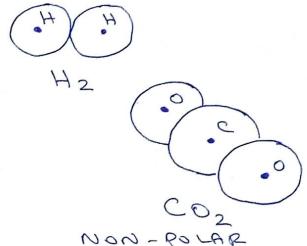
Eg: H2O, HCD, N2O

NON POLAR MOLECULE

A non pology molecule is one in which the centre of growity of the positive changes coincides with centre of growity of negative electrons.



POLAR MOLECULE



NON-POLAR MOLECULE

## ORIENTATION POLARIZATION

\* It takes place only in polos dielectorics

\* Polos dielectorics have molecules with

Permanent dipole moments even in the absence

of electorical Sield.

when we polosi dielectrics one subjected dipoles to an electrical field, we molecules are opiented in direction of electric field.

The Polosiization due to orientation of molecular dipoles is called orientational Polosization.

ogient ational polari zation depends on temperature. when temperature is increased, meanal energy tends to disturb the alignment

Forom Langevin's messy of Passamagnetism,

Same parinciple is applied here,

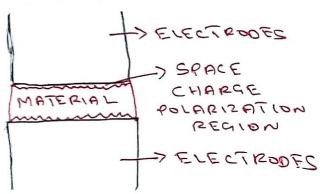
Considerional Rolandia

Po - NLOE

Lo - ogientational polarizability

## SPACE CHARGE POLARIZATION

Space change poparization occurs due to one accumulation of changes at the electrodes on at the intersaces of multiphase dielectric materials.



INTERNAL FIELD OF SOLIDS

when a dielectaic

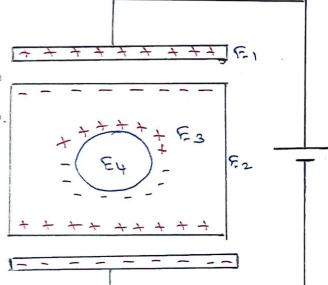
material is placed between

two payallel Plate capacitosss.

The internal field of

solid consitutes of 50091

Components.



Eint = E1 + E2 + E3 + E4

En- Field describer due to chonges on possible

Ez-Electoric Sield intensity due to change density on side of dielectoric material

Ez-Field intensity due to other atoms in dielectric material

Ey - Electric sield intensity due to change density on suppace of cavity.

The electoric sield intensity due to changes on me plates,

D-Displacement consient which or elates line electoric field & polodization

$$D = \varepsilon_0 E + P$$

$$E_1 = \varepsilon_0 E + P$$

$$\varepsilon_0$$

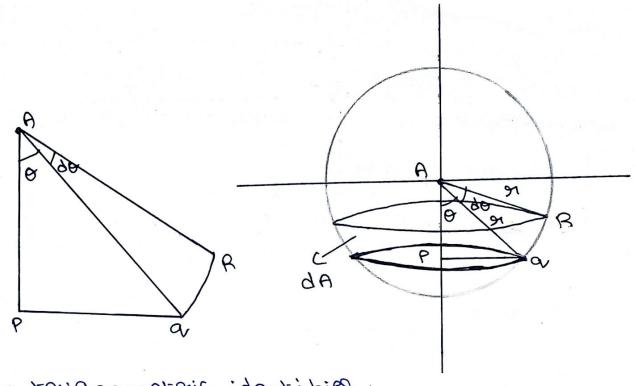
Ez-Field intensity due to change density on eimon side of dielectoric

$$E_2 = -P$$
 $E_0$ 

F3 - consider one diplectoric material to have cubic stoucture where the dipole moments cancel each owner.

consider a covity in we dielecteric material with a spherical shape of gradius 9.

Let us absume two small sugniface oned whose onea is dA



Sing = 088

9EN

By torignometoric identities

DAPQ

SIND - POV

91

Par = 91 sino

DANR

- 8

Sinde = OR

by small angle approximation

Sin do = do

:. do = ar

OB = 9160

dA = 277 x91 Sin0 x91 do

dA = 2TT 912 Sind do -> 1

changes da paresent in sunface onea dA

13

da = PCOSE dA da from earation 1 da = PCOSO (2TT912 SINO de) -> 2 Electoric field at centure point Ais, dE4 = da 4TT E0912 0=0, normal electric sield intensity dE4 = da coso 4TT E0912 Substitute da som eauation 2 GEH = 60000 (XXXX SIUBGB) X COZO 47/ E0 9/2 de4 = P cos2 & sine de E4 = ) dE4 E4 = Sp cos2 & sind do  $E_{4} = \frac{P}{2E_{0}} \int \cos^{2}\theta \sin\theta d\theta$ 

Estimil and enistablia

$$\frac{\cos \theta = 1}{2\varepsilon_0} \cos \pi = -1$$

$$\frac{2\varepsilon_0}{2\varepsilon_0} \cos \pi = -1$$

$$E_4 = \frac{P}{2\varepsilon_0} \frac{\chi^3}{3}$$

$$E_{4} = \frac{P}{2\epsilon_{0}} \left[ \frac{1}{3} + \frac{1}{3} \right]$$

Lord income Sield

$$\frac{1}{16} = \frac{1}{16} = \frac{1}{16}$$

$$E_{int} = E + \frac{P}{\varepsilon_0} - \frac{P}{\varepsilon_0} + 0 + \frac{P}{3\varepsilon_0}$$

# C'LAUSIUS MOSSOTTIE QUATION

chausius mossotti gelates me electronic pologic ability and me dielectric constant of a diffectoric material.

En - dielectaic constant

E- Matorial permittivity

Eo - Vacoum pomittivity

Let N- number of moderales in the medium

& - electronic Pologizability

P- Total Polonization

Fint - 70-02 invernal field of a solid

cumplent density

Eine = P 
$$\left(\frac{1}{\varepsilon-\varepsilon_{0}} + \frac{1}{3\varepsilon_{0}}\right)$$

Eine = P  $\left(\frac{3\varepsilon_{0} + \varepsilon_{0}}{3\varepsilon_{0}(\varepsilon-\varepsilon_{0})}\right)$ 

Eine = P  $\left(\frac{2\varepsilon_{0} + \varepsilon_{0}}{3\varepsilon_{0}(\varepsilon-\varepsilon_{0})}\right)$ 

Eine = P  $\left(\frac{2\varepsilon_{0} + \varepsilon_{0}}{\varepsilon-\varepsilon_{0}}\right)$ 

Eine = P  $\left(\frac{2\varepsilon_{0} + \varepsilon_{0}}{\varepsilon-\varepsilon_{0}}\right)$ 

Now =  $\left(\frac{\varepsilon-\varepsilon_{0}}{2\varepsilon_{0} + \varepsilon_{0}}\right)$ 

Now =  $\left(\frac{\varepsilon-\varepsilon_{0}}{2\varepsilon_{0} + \varepsilon_{0}}\right)$ 

Now =  $\left(\frac{\varepsilon}{2\varepsilon_{0} + \varepsilon_{0}}\right)$ 
 $\left(\frac$ 

The above grelation is Clausius mossotti gelation.

## DIELECTRIC LOSS

when a dielectric material is applied with Acvortage, the electrical energy is absorbed by the dielectric and certain avantity of electrical energy is dissipated in the form of heat energy is teamed as dielectric loss.